

## Differential Hall-Effect Spectroscopy (DHES)

### for p-type semiconductor

The hole concentration  $p(T)$  produced by  $n$  different acceptor species (density  $N_{Ai}$  and energy level  $E_{Ai}$ ) and one donor (density  $N_D$ ) is expressed by

$$p(T) = \sum_{i=1}^n \frac{N_{Ai}}{1 + g \exp\left(\frac{E_{Ai} - E_F}{kT}\right)} - N_A. \quad (1)$$

The derivative  $kT \cdot dp(T)/dE_F$  is derived as

$$\begin{aligned} kT \frac{dp(T)}{dE_F} &= -kT \sum_{i=1}^n N_{Ai} \frac{\frac{\partial}{\partial E_F} \left[ 1 + g \exp\left(\frac{E_{Ai} - E_F}{kT}\right) \right] + \frac{\partial}{\partial (kT)} \left[ 1 + g \exp\left(\frac{E_{Ai} - E_F}{kT}\right) \right] \frac{\partial (kT)}{\partial E_F}}{\left[ 1 + g \exp\left(\frac{E_{Ai} - E_F}{kT}\right) \right]^2} \\ &= kT \sum_{i=1}^n N_{Ai} \frac{\frac{g}{kT} \exp\left(\frac{E_{Ai} - E_F}{kT}\right) + g \frac{E_{Ai} - E_F}{(kT)^2} \exp\left(\frac{E_{Ai} - E_F}{kT}\right) \frac{\partial (kT)}{\partial E_F}}{\left[ 1 + g \exp\left(\frac{E_{Ai} - E_F}{kT}\right) \right]^2} \\ &= \sum_{i=1}^n N_{Ai} \frac{g \exp\left(\frac{E_{Ai} - E_F}{kT}\right)}{\left[ 1 + g \exp\left(\frac{E_{Ai} - E_F}{kT}\right) \right]^2} \cdot \left[ 1 + \frac{E_{Ai} - E_F}{kT} \cdot \frac{\partial (kT)}{\partial E_F} \right] \end{aligned} \quad (2)$$

Since energy levels measured from the top of the valence band are described as

$$\Delta E_{Ai} = E_{Ai} - E_V \quad (3)$$

and

$$\Delta E_F = E_F - E_V, \quad (4)$$

the DHES signal is theoretically expressed by

$$DHES[\Delta E_F(T)] = \sum_{i=1}^n N_{Ai} \frac{g \exp\left(\frac{\Delta E_{Ai} - \Delta E_F}{kT}\right)}{\left[ 1 + g \exp\left(\frac{\Delta E_{Ai} - \Delta E_F}{kT}\right) \right]^2} \cdot \left[ 1 + \left( \frac{\Delta E_{Ai} - \Delta E_F}{kT} \right) \cdot \frac{\partial (kT)}{\partial \Delta E_F} \right]. \quad (5)$$

The function

$$N_{Ai} \frac{g \exp\left(\frac{\Delta E_{Ai} - \Delta E_F}{kT}\right)}{\left[ 1 + g \exp\left(\frac{\Delta E_{Ai} - \Delta E_F}{kT}\right) \right]^2}$$

has a maximum of

$$\frac{N_{Ai}}{4}$$

at  $\Delta E_F = \Delta E_{Ai} + kT_{\max} \ln g$ .